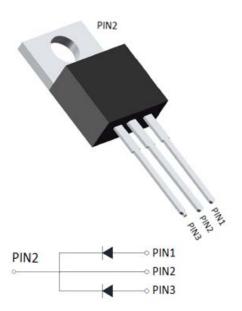
MBR1580CT THRU MBR15200CT



Schottky Diodes



Features

- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

• Package: TO-220AB

Molding compound meets UL 94 V-0 flammability

rating, RoHS-compliant

• Terminals: Tin plated leads, solderable per J-STD-

002 and JESD22-B102

• Polarity: As marked

■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR1580CT	MBR1590CT	MBR15100CT	MBR15120CT	MBR15150CT	MBR15200CT
Device marking code			MBR1580CT	MBR1590CT	MBR15100CT	MBR15120CT	MBR15150CT	MBR15200CT
Repetitive Peak Reverse Voltage	VRRM	V	80	90	100	120	150	200
Average Rectified Output Current @60Hz sine wave, R-load, T _a =25℃	Ю	Α	15					
Surge(Non-repetitive)Forward Current @60H _Z half sine-wave, 1 cycle, T _a =25°C	IFSM	А	150					
Current Squared Time @1ms≤t<8.3ms Tj=25°C,	l ² t	A ² s	94					
Storage Temperature	T _{stg}	$^{\circ}$	-55 ~ + 150					
Junction Temperature	Tj	$^{\circ}$	-55 ~ +150					

■Electrical Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBR1580CT	MBR1590CT	MBR15100CT	MBR15120CT	MBR15150CT	MBR15200CT
Maximum instantaneous forward voltage drop per diode	VFM	V	IFM=7.5A	0.85		0.	9	0.95	
Maximum DC reverse current	IRRM1	•	VRM=VRRM T _a =25°C				0.1		
at rated DC blocking voltage per diode				20					

MBR1580CT THRU MBR15200CT

■Thermal Characteristics (T_a=25°C Unless otherwise specified)

PARA	AMETER	SYMBOL	UNIT	MBR1580CT	MBR1590CT	MBR15100CT	MBR15120CT	MBR15150CT	MBR15200CT
Thermal Resistance	Between junction and case	R _{θJ-C}	°CMV	2.0					

■Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBR1580CT THRU MBR15200CT	Approximate 1.9	50	1000	5000	Tube

■Characteristics (Typical)

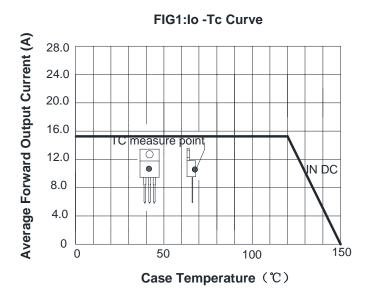
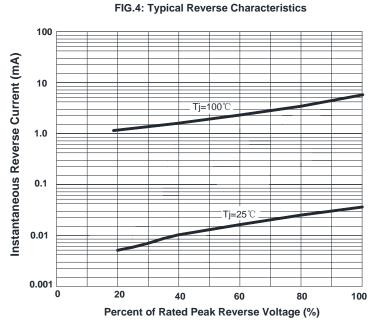


FIG2:Surge Forward Current Capability 175 Peak Forward Surge Current (A) 150 125 8.3ms Single Half Sine-Wave 100 JEDEC Method 75 50 25 10 50 100 **Number of Cycles**

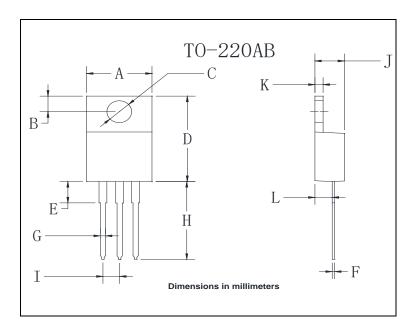
FIG3: Forward Voltage 60 20 Instantaneous Forward Current (A) 80V~|100V 10 5.0 150V 1.0 0.2 Ta=25℃ 0.3 0.2 0.7 0.8 0.9 Instantaneous Forward Voltage (V)



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MBR1580CT THRU MBR15200CT

■Outline Dimensions



TO-220AB						
Dim	Min	Max				
Α	9.5	10.9				
В	2.22	3.27				
С	3.34	4.31				
D	14.5	15.5				
Е	3.16	4.46				
F	0.28	0.64				
G	0.68	0.94				
Н	13.06	14.62				
I	2.01	3.07				
J	4.04	5.1				
K	1.14	1.4				
L	2.14	3.19				

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